

NE85639-T1-R28-A

NE85639-T1-R28-A Information

Heisener.com	Part Number Manufacturer Category Description Package	NE85639-T1-R28-A CEL Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF SAME AS 2SC4093 NPN SILICON AMPL TO-253-4, TO-253AA For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NE85639-T1-R28-A Specifications

Manufacturer Part Number	NE85639-T1-R28-A
Manufacturer	CEL
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-253-4, TO-253AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	9GHz
Noise Figure (dB Typ @ f)	1.1dB @ 1GHz
Gain	13dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 20mA, 10V
Current - Collector (Ic) (Max)	100mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-253-4, TO-253AA
Supplier Device Package	SOT-143
	Report errors?

NE85639-T1-R28-A Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NE85639-T1-R28-A Payment Methods



NE85639-T1-R28-A Shipping Methods



If you have any question about NE85639-T1-R28-A, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com